

substance: V_2O_3

property: transport properties, low-temperature phase, $T < T_{\text{tr}}$

resistivity

ρ	$0.5 \cdot 10^4 \Omega \text{ cm}$	$\parallel c, T = 132 \text{ K}$	activation energy 0.12 eV	67F
	$1.3 \cdot 10^4 \Omega \text{ cm}$	$\parallel b, T = 132 \text{ K}$	activation energy 0.18 eV	

For stress X the resistivity varies as $\rho(X, T) = A(0) \exp((E + aX)/kT)$ with $a = -1.5 \cdot 10^{-6} \text{ eV bar}^{-1}$ for uniaxial stress along b -axis, $= -1.1 \cdot 10^{-6} \text{ eV bar}^{-1}$ for hydrostatic pressure [67F].

variation of the transition temperature with uniaxial stress

dT_{tr}/dX	$-6.8(5) \cdot 10^{-3} \text{ K bar}^{-1}$	$X \parallel a$	67F
	$-4.1(5) \cdot 10^{-3} \text{ K bar}^{-1}$	$X \parallel b$	
	$-0.5(5) \cdot 10^{-3} \text{ K bar}^{-1}$	$X \parallel c$	

Seebeck coefficient: Fig. 1. S is large and negative.

Hall data: No data reported.

transport properties for V_2O_{3+x} : Fig. 2. No semiconducting phase formed for $x \geq 0.04$. Discontinuity in resistivity $\Delta\rho$ is independent of x ; $\Delta\rho \approx 10^7 \Omega \text{ cm}$ at T_{tr} [80U]. T_{tr} decreases with x (Fig. 3).

high-temperature transition: $\rho(T)/\rho(0^\circ\text{C})$ rises anomalously rapidly in the region of 525 K.

Cr doped material: Conductivity: Fig. 4, Seebeck coefficient: Fig. 5, conductivity of $(\text{V}_{1-x}\text{Cr}_x)_2\text{O}_{3+y}$, Fig. 6.

Al doped material: Conductivity: Fig. 7.

Ti doped material: Conductivity: Fig. 8.

References:

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- 76K2 Kuwamoto, H., Keer, H. V., Keem, J. E., Shivashenkar, S., Van Zandt, L. L., Honig, J. M.: J. Phys. 37 (1976) C4-35.
- 80K1 Kuwamoto, H., Honig, J. M., Appel, J.: Phys. Rev. B22 (1980) 2626.
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V₂O₃. Seebeck coefficient vs. temperature for pure and Ti-doped V₂O₃. Downward triangles: first cooling, full circles: second cooling, upward triangles: second warming, downward full triangles: 0.1 at% Ti, upward full triangles: 1 at% Ti. A second sample was also investigated, (o) cooling [75K]. Orientation not given.

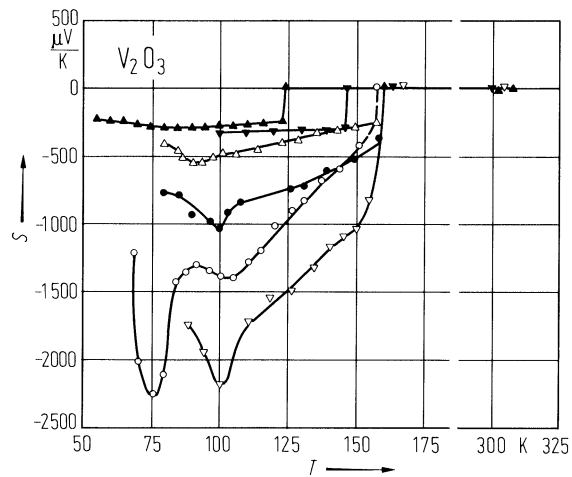


Fig. 2.

V_2O_{3+x} . Resistivity vs. temperature on cooling [80U]. Orientation not given.

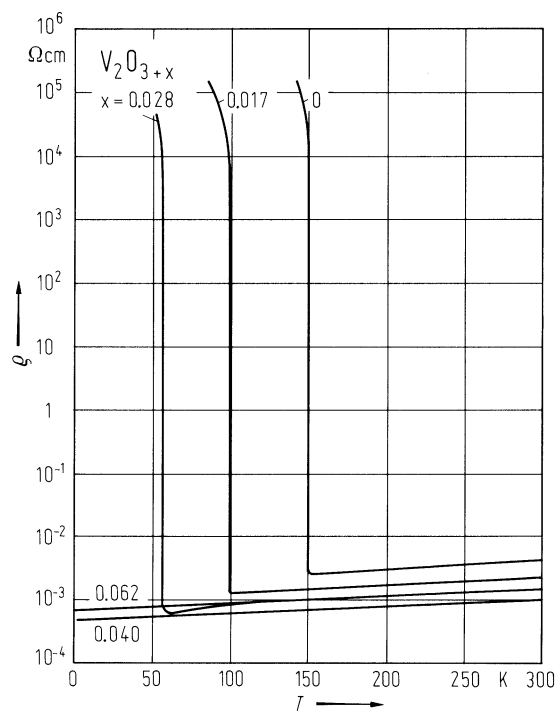


Fig. 3.

V_2O_{3+x} , $(V_{1-x}Ti_x)_2O_3$. Comparison of activation energy E_A and discontinuity in resistivity ($\Delta\rho$) vs. transition temperature T_{tr} [80U]. $\Delta\rho = \rho(T < T_{tr}) - \rho(T > T_{tr})$.

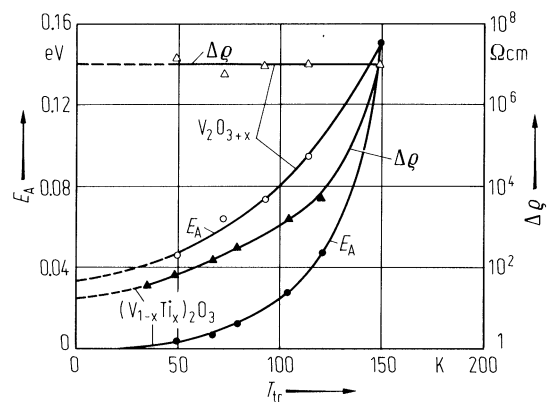


Fig. 4.

$(V_{1-x}Cr_x)_2O_3$. Resistivity vs. reciprocal temperature [80K1]. Orientation not given.

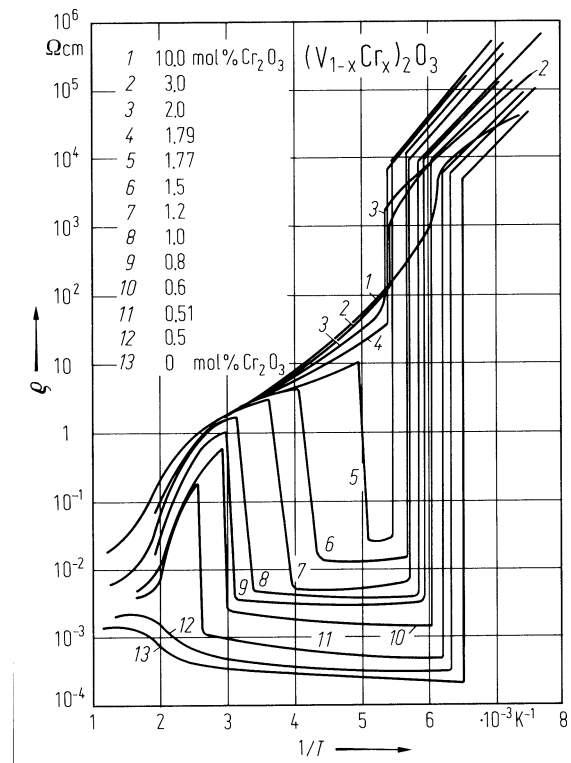


Fig. 5.

$(V_{1-x}Cr_x)_2O_3$. Seebeck coefficient vs. temperature [80K1]. Orientation not given.

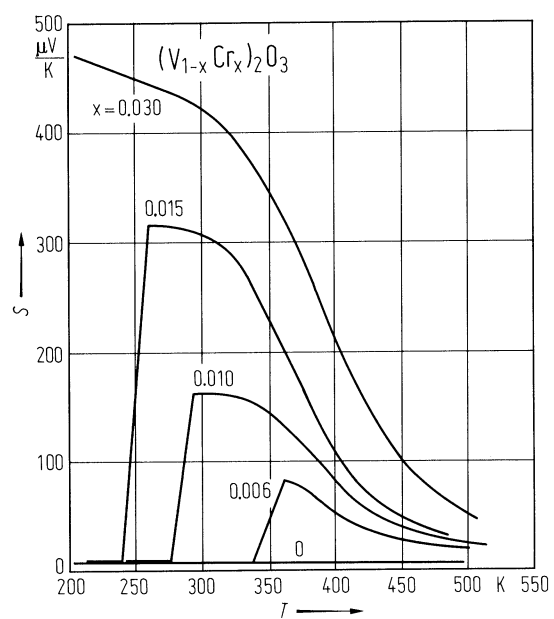


Fig. 6.

$(V_{1-x}Cr_x)_2O_{3+y}$. Resistivity vs. reciprocal temperature [80K2]. Orientation not given.

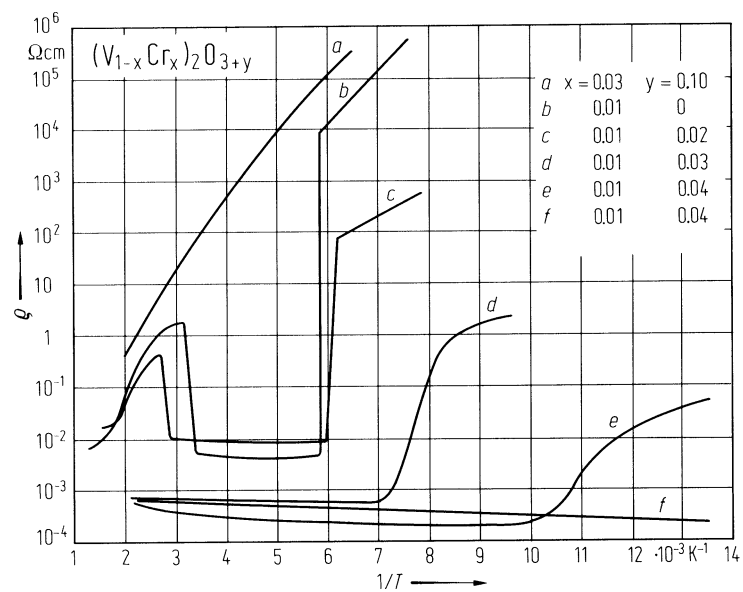


Fig. 7.

$(V_{1-x}Al_x)_2O_3$. Electrical resistivity vs. reciprocal temperature for (curve a) $x = 0.0033$, (b) $= 0.011$, (c) $= 0.02$ [76K1]. Orientation not given.

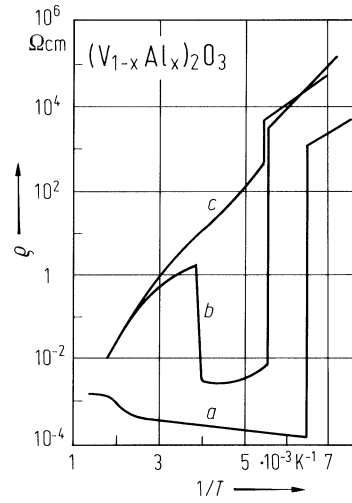


Fig. 8.

$(V_{1-x}Ti_x)_2O_3$. Electrical resistivity vs. reciprocal temperature [76K2]. Orientation not given.

